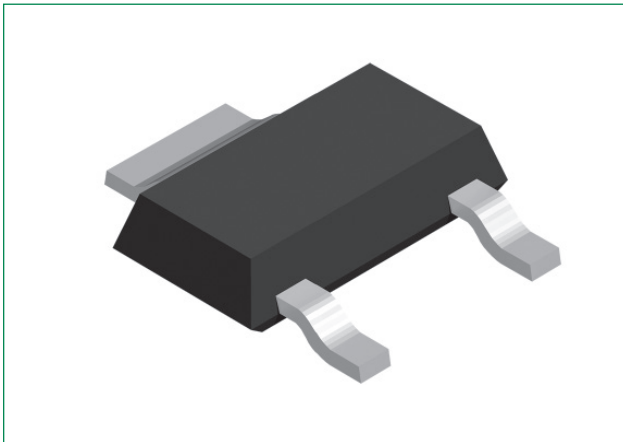


# CPC3981Z

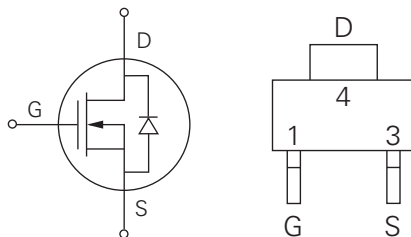
## 800V, 45Ω N-Channel MOSFET

### Key Attributes

Characteristic	Rating	Unit
$V_{(BR)DSX}$	800	V
$T_J$	150	°C
$R_{DS(on)}$	45	Ω
$I_{DSS}$	100	mA



### Pinout Diagram (SOT-223-2L)



**G:** Gate; **D:** Drain; **S:** Source

### Description



The CPC3981Z is an 800V, N-channel, depletion-mode, Field Effect Transistor (FET) in a modified SOT-223 package to provide greater separation of the drain and source leads for high voltage applications.

The CPC3981Z's robust MOSFET has been used extensively in Littelfuse Integrated Circuits' Solid State Relays in power, industrial, and telecommunications applications.

The CPC3981Z is available in the SOT-223-2L package.

### Features & Benefits

- 800V breakdown voltage
- 45Ω on-resistance
- $V_{GS(off)}$ : -1.4V to -3.1V
- $T_J(max)$ : 150°C
- High input impedance

### Applications

- Normally on switches
- Solid state relays
- Converters
- Telecommunications
- Power supplies
- Current regulators

### Ordering Information

Part #	Description
CPC3981ZTR	SOT-223-2L: Tape and Reel (3000/Reel)

## Absolute Maximum Ratings

Parameter	Rating	Unit
Drain-to-Source Voltage	800	V
Gate-to-Source Voltage	±15	V
Pulsed Drain Current	150	mA
Total Package Dissipation <sup>1</sup>	2.25	W
Operational Temperature, Ambient	-55 to +150	°C
Junction Temperature, Maximum	+150	°C
Storage Temperature	-55 to +150	°C

<sup>1</sup> Mounted on 1"x1" 2 oz. Copper FR4 board.

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied. Absolute Maximum Ratings are at  $T_A = 25^\circ\text{C}$ .

Unless otherwise specified, device characteristics are at  $T_A = 25^\circ\text{C}$ . Typical values are characteristic of the device at  $T_A = 25^\circ\text{C}$  and are the result of engineering evaluations. They are provided for informational purposes only and are not part of the manufacturing testing requirements.

## Electrical Characteristics

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSX}$	$V_{GS} = -5.5\text{V}, I_D = 1\mu\text{A}$	800	-	-	V
Gate-to-Source Off Voltage	$V_{GS(off)}$	$V_{DS} = 15\text{V}, I_D = 1\mu\text{A}$	-1.4	-	-3.1	V
Change in $V_{GS(off)}$ with Temperature	$dV_{GS(off)}/dT$	$V_{DS} = 15\text{V}, I_D = 1\mu\text{A}$	-	-	-6.3	mV/°C
Gate Leakage Current	$I_{GSS}$	$V_{GS} = \pm 15\text{V}, V_{DS} = 0\text{V}$	-	-	100	nA
Drain-to-Source Off-state Leakage Current	$I_{D(off)}$	$V_{GS} = -5.5\text{V}, V_{DS} = 800\text{V}$	-	-	1	$\mu\text{A}$
Saturated Drain-to-Source Current	$I_{DSS}$	$V_{GS} = 0\text{V}, V_{DS} = 15\text{V}$	100	-	-	mA
Static Drain-to-Source On-State Resistance*	$R_{DS(on)}$	$V_{GS} = 0\text{V}, I_D = 100\text{mA}$	-	32.5	45	$\Omega$
Change in $R_{DS(on)}$ with Temperature	$dR_{DS(on)}/dT$		-	-	2.5	%/°C
Forward Transconductance	$g_{fs}$	$I_D = 50\text{mA}, V_{DS} = 10\text{V}$	100	-	-	mS
Input Capacitance	$C_{ISS}$	$V_{GS} = -3.5\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$	-	105	-	$\text{pF}$
Output Capacitance	$C_{OSS}$		-	7.5	-	
Reverse Transfer Capacitance	$C_{RSS}$		-	2.75	-	
Drain-Source Reverse Voltage	$V_{SD}$	$V_{GS} = -5.5\text{V}, I_S = 100\text{mA}$	-	0.67	0.95	V

\*Measurement taken within 500 $\mu\text{s}$

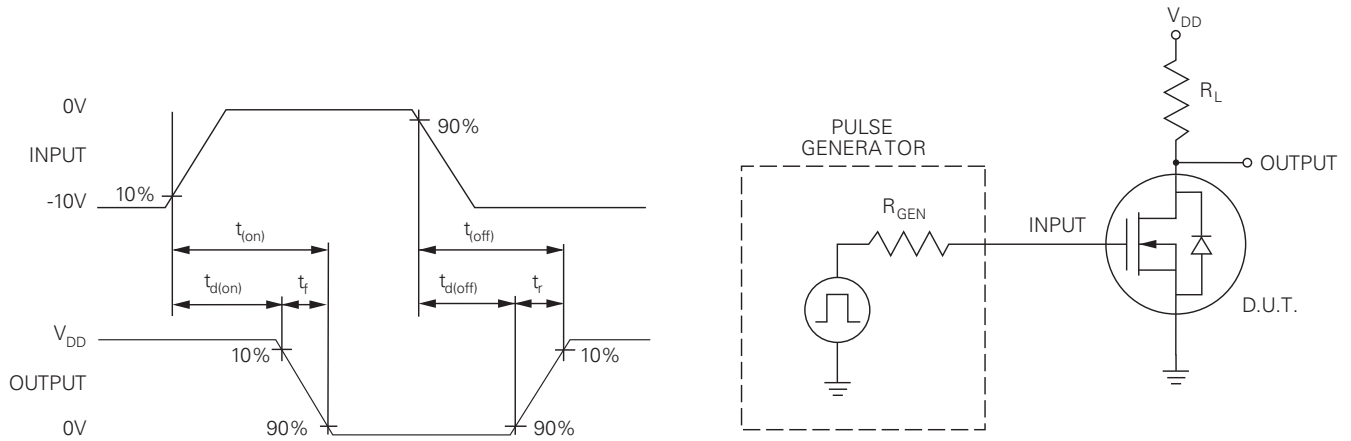
## Timing Characteristics

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 25\text{V}, I_D = 50\text{mA}, V_{GS} = 0\text{V to } -10\text{V},$ $R_{GEN} = 50\Omega$	-	79.2	170	ns
Fall Time	$t_f$			34.9	145	
Turn-Off Delay Time	$t_{d(off)}$			25.3	65	
Rise Time	$t_r$			19.7	35	

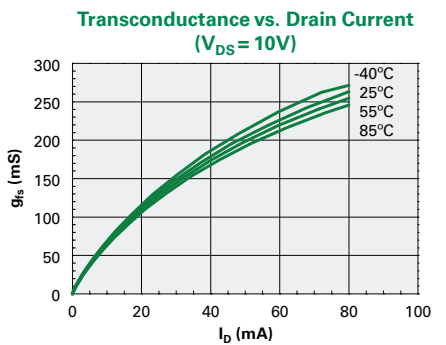
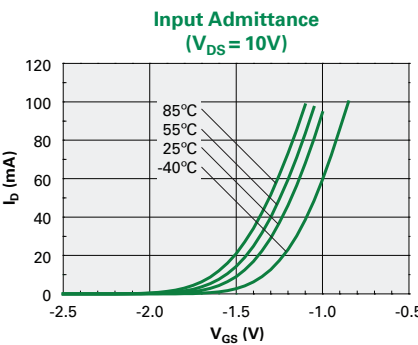
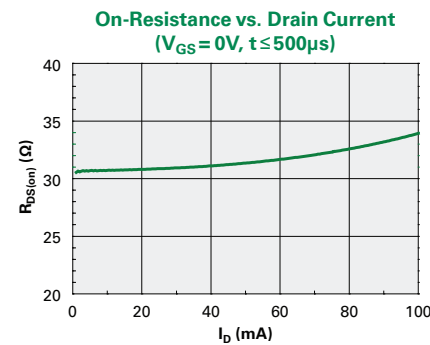
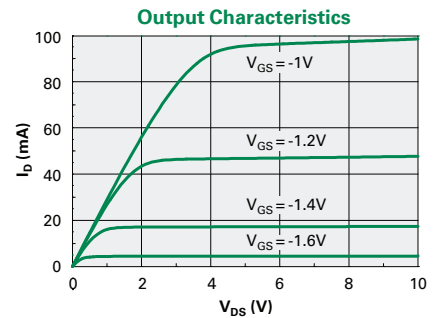
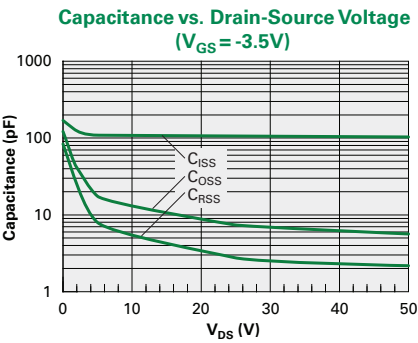
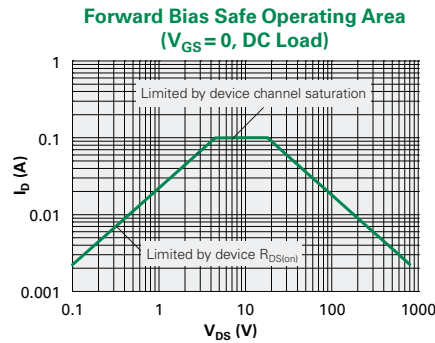
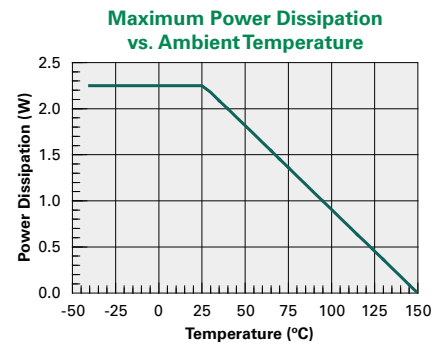
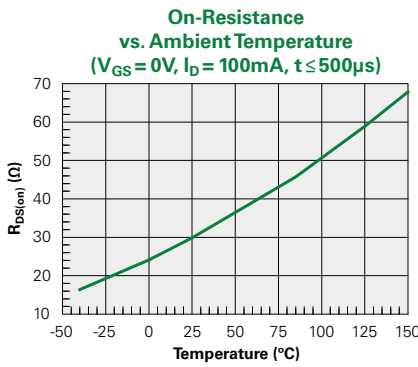
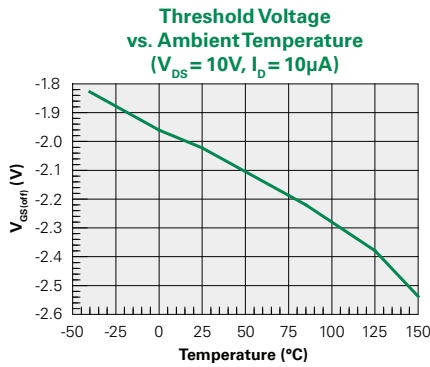
## Thermal Characteristics

Parameter	Symbol	Rating	Unit
Thermal Resistance			
Junction to Ambient	$R_{th(J-A)}$	55	°C/W
Junction to Case	$R_{th(J-C)}$	23	

### Switching Waveform & Test Circuit



### Characteristic Curves\*



\*Unless otherwise noted, data presented in these graphs is typical of device operation at  $T_A = 25^\circ C$ .

## Manufacturing Information

### Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Littelfuse classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, IPC/JEDEC J-STD-020, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a Moisture Sensitivity Level (MSL) classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard IPC/JEDEC J-STD-033.

Device	Moisture Sensitivity Level (MSL) Classification
CPC3981Z	MSL 3

### ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard JESD-625.

### Soldering Profile

Provided in the table below is the IPC/JEDEC J-STD-020 Classification Temperature ( $T_C$ ) and the maximum total dwell time ( $t_p$ ) in all reflow processes that the body temperature of these surface mount devices may be ( $T_C - 5$ )°C or greater. The device's body temperature must not exceed the Classification Temperature at any time during reflow soldering processes.

Device	Classification Temperature ( $T_C$ )	Dwell Time ( $t_p$ )	Max Reflow Cycles
CPC3981Z	260°C	30 seconds	3

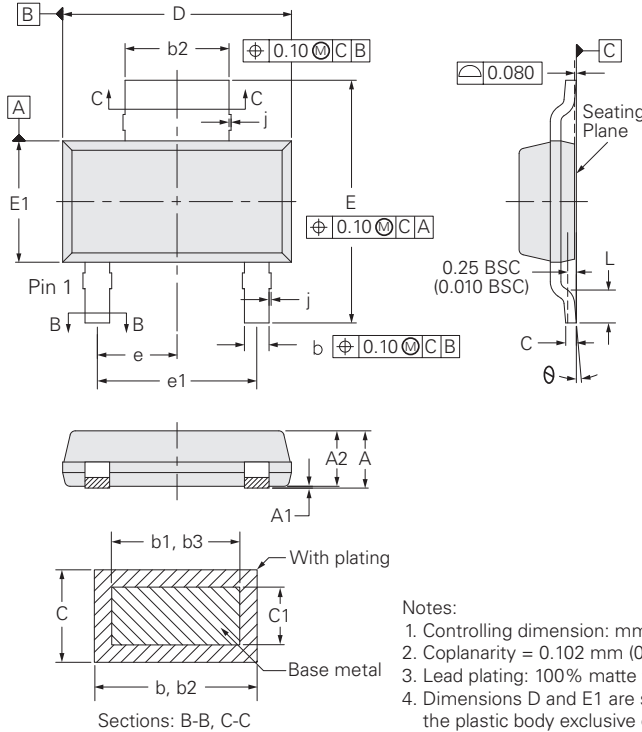
### Board Wash

Littelfuse recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

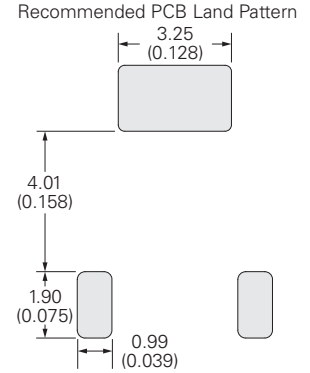


### Mechanical Dimensions

#### CPC3981Z Part Outline Drawing and PCB Land Pattern

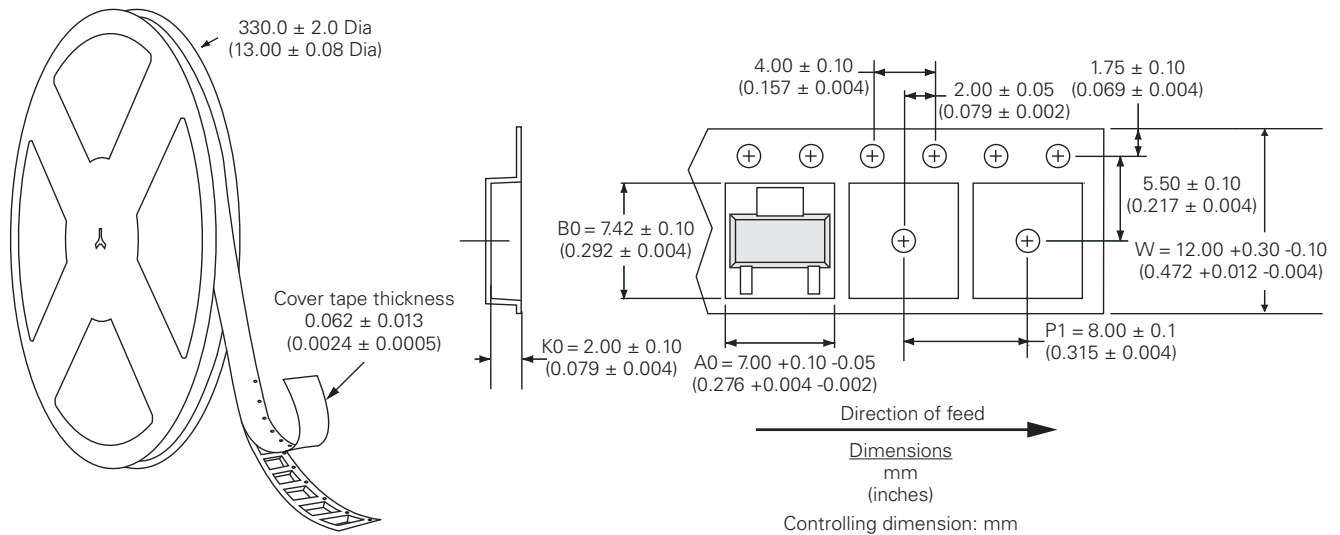


Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	-	1.80	-	0.071
A1	0.02	0.10	0.001	0.004
A2	1.50	1.70	0.059	0.067
b	0.66	0.84	0.026	0.033
b1	0.60	0.79	0.024	0.031
b2	2.90	3.10	0.114	0.122
b3	2.84	3.05	0.112	0.120
c	0.23	0.35	0.009	0.014
c1	0.23	0.33	0.009	0.013
D	6.30	6.70	0.248	0.264
E	6.70	7.30	0.264	0.287
E1	3.30	3.70	0.130	0.146
e	2.30 BSC		0.091 BSC	
e1	4.60 BSC		0.182 BSC	
L	0.81	1.10	0.032	0.043
θ	0°	10°	0°	10°
j	-	0.13	-	0.005



- Notes:
1. Controlling dimension: mm
  2. Coplanarity = 0.102 mm (0.004") max
  3. Lead plating: 100% matte tin, 1000 pinches max
  4. Dimensions D and E1 are specified at the outermost edges of the plastic body exclusive of mold flash, burrs, and interlead flash.

#### CPC3981ZTR Tape & Reel



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